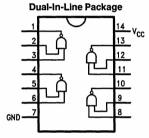


DM96101 Quad 2-Input Positive NAND Buffer with Open-Collector Output

General Description

The DM96101 is similar to the 54/7439, except that the outputs are specified at three levels of I_{OL} ; in the HIGH state the I_{OH} current is specified at two levels of V_{OH} . During switching transitions, output current change rate is typically 4.0 mA/ns.

Connection Diagram



Order Number DM96101N Se NS Package Number N14A TL/F/9799-1

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V Input Voltage 5.5V Operating Free Air Temperature Range 0° C to $+70^{\circ}$ C Storage Temperature Range -65° C to $+150^{\circ}$ C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	Min	Nom	Max	Units
V _{CC}	Supply Voltage	4.75	5	5.25	V
V _{IH}	High Level Input Voltage	2			V
V _{IL}	Low Level Input Voltage			0.8	V
Іон	High Level Output Current			-0.05	mA
loL	Low Level Output Current			16	mA
T _A	Free Air Operating Temperature	0		70	°C

Electrical Characteristics

Over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
V ₁	Input Clamp Voltage	$V_{CC} = Min, I_1 = -12 \text{ mA}$				-1.5	٧
V _{OH}	High Level Output Voltage	V _{CC} = Min, I _{OH} = Max V _{IL} = Max		2.4	3.4		٧
0.	Low Level Output Voltage	$V_{CC} = Min,$ $V_{IH} = V_{IN}$	$I_{OL} = 48 \text{ mA}$			0.4	V
			$I_{OL} = 60 \text{ mA}$			0.5	
			$I_{OL} = 80 \text{ mA}$			0.6	
կ	Input Current @ Max Input Voltage	$V_{CC} = Max, V_{I} = 5.5V$				1	mA
l _{IH} High	High Level Input Current	V _{CC} = Max	V _{IN} = 2.4V			40	μΑ
			$V_{IN} = 5.5V$			1000	
l _{IL}	Low Level Input Current	$V_{CC} = Max, V_{IN} = 0.4V$				-1.6	mA
los	Short Circuit Output Current	V _{CC} = Max (Note 2)		-18		-57	mA
ГССН	Supply Current with Outputs High	V _{CC} = Max, V _{IN} = 0V				8.5	mA
ICCL	Supply Current with Outputs Low	V _{CC} = Max, V _{IN} = Open				54	mA

$\textbf{Switching Characteristics} \text{ at V}_{CC} = 5 \text{V and T}_{A} = 25^{\circ}\text{C (See Section 1 for Test Waveforms and Output Load)}$

Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Time Low to High Level Output	$C_L = 45 pF$ $R_L = 120 \Omega$		22	ns
t _{PHL}	Propagation Delay Time High to Low Level Output			25	ns

Note 1: All typicals are at $V_{CC} = 5V$, $T_A = 25$ °C.

Note 2: Not more than one output should be shorted at a time.